SGS-THOMSON MICROELECTRONICS

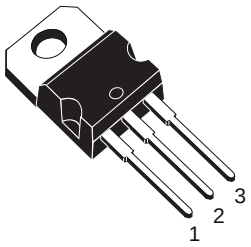
BUV28

SILICON NPN SWITCHING TRANSISTOR

- SGS-THOMSON PREFERRED SALESTYPE
- NPN TRANSISTOR
- VERY LOW SATURATION VOLTAGE
- FAST TURN-OFF AND TURN-ON

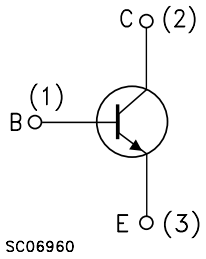
APPLICATIONS:
- SWITCHING REGULATORS
- SOLENOID / RELAY DRIVERS

DESCRIPTION
High speed transistor suited for low voltage applications.
High frequency and efficiency converters switching regulators motor control.



TO-220

INTERNAL SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-base Voltage (I_E = 0)	400	V
V_{CEO}	Collector-Emitter Voltage (I_B = 0)	200	V
V_{EBO}	Emitter-Base Voltage (I_C = 0)	7	V
I_C	Collector Current	10	A
I_{CM}	Collector Peak Current	15	A
I_B	Base Current	2	A
I_{BM}	Base Peak Current	4	A
P_{tot}	Total Dissipation at Tc < 25 °C	85	W
P_{tot}	Total Dissipation at T_c < 60 °C	65	W
T_{stg}	Storage Temperature	-65 to +175	°C
T_j	Max. Operating Junction Temperature	175	°C

THERMAL DATA

$R_{thj\text{-}case}$	Thermal Resistance Junction-case	Max	1.76	$^oC/W$

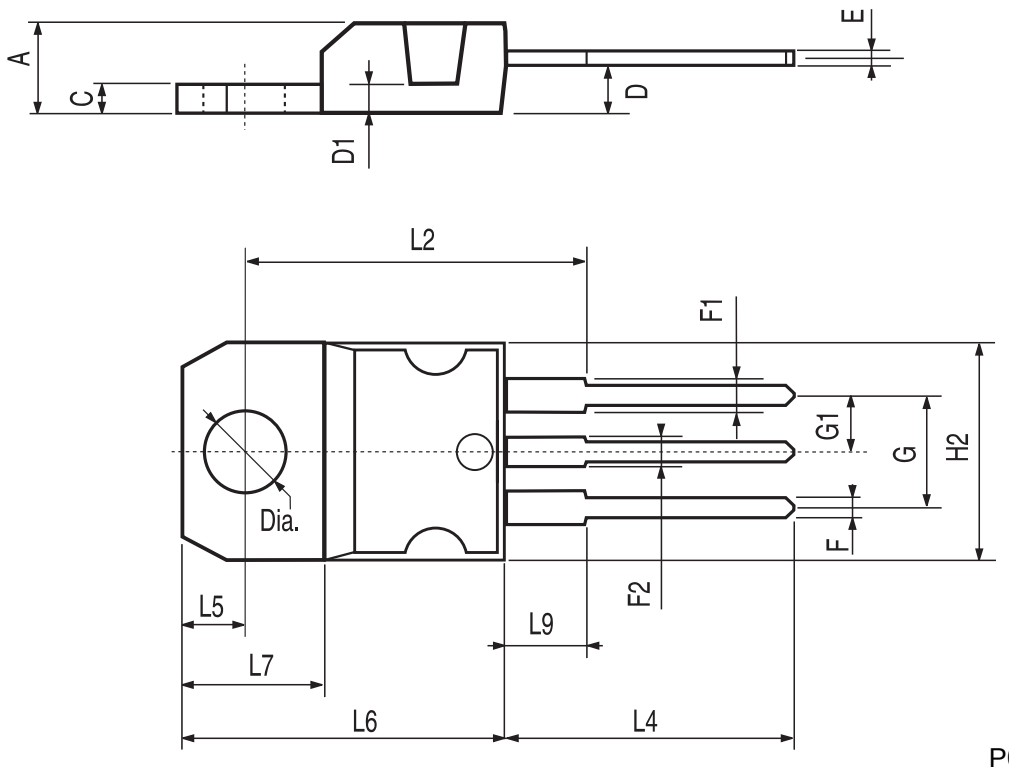
ELECTRICAL CHARACTERISTICS (T_{case} = 25 ^oC unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CER}	Collector Cut-off Current (R_{BE} = 50Ω)	V_{CE} = 400V T_c = 125^oC			3	mA
I_{CEX}	Collector Cut-off Current	V_{CE} = 400V V_{BE} = -1.5V T_c = 125^oC			1	mA
I_{EBO}	Emitter Cut-off Current (I_C = 0)	V_{EB} = 5 V			1	mA
$V_{CEO(sus)}$*	Collector-Emitter Sustaining Voltage	I_C = 0.2 A L = 25mH	200			V
V_{EBO}	Emitter-Base Voltage (I_C = 0)	I_E = 50mA	7		30	V
$V_{CE(sat)}$*	Collector-Emitter Saturation Voltage	I_C = 3A I_B = 0.3A I_C = 6A I_B = 0.6A			0.7 1.5	V V
$V_{BE(sat)}$*	Base-Emitter Saturation Voltage	I_C = 6A I_B = 0.6A			2	V
	RESISTIVE LOAD					
t_{on}	Storage Time	V_{CC} = 150V I_C = 6A		0.3	1	µs
t_s	Fall Time	V_{BE} = - 6V I_{B1} = 0.6A		0.5	1.5	µs
t_f	Turn-on Time	R_{BB} = 5Ω		0.1	0.25	µs
	INDUCTIVE LOAD					
t_s	Storage time	V_{CC} = 150V I_C = 6A		1		µs
t_f	Fall Time	I_{B1} = 0.6A V_{BE} = - 5V L_B =1µH		0.04		µs
t_s	Storage Time	V_{CC} = 150V I_C = 6A			3	µs
t_f	Fall Time	I_{B1} = 0.6A V_{BE} = - 5V L_B = 1µH T_j = 125^oC			0.2	µs

* Pulsed: Pulse duration = 300µs, duty cycle = 2 %

TO-220 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.40		4.60	0.173		0.181
C	1.23		1.32	0.048		0.051
D	2.40		2.72	0.094		0.107
D1		1.27			0.050	
E	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.203
G1	2.4		2.7	0.094		0.106
H2	10.0		10.40	0.393		0.409
L2		16.4			0.645	
L4	13.0		14.0	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.2		6.6	0.244		0.260
L9	3.5		3.93	0.137		0.154
DIA.	3.75		3.85	0.147		0.151



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